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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Appln. Of: ASPAR et al.

Serial No.:

10/784,601

Filed:

February 23, 2004

For:

A METHOD FOR PRODUCING A THIN LAYER OF SEMICONDUCTOR

MATERIAL

Group:

2823

Confirmation No. 8343

Examiner:

Fourson, III, George R.

DOCKET: BREV 12370 CON4

MAIL STOP ISSUE FEE Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## AMENDMENT UNDER RULE 312 AND COMMENTS ON STATEMENT OF REASONS FOR ALLOWANCE

Dear Sir:

This Amendment is being filed in response to the Notice of Allowance mailed September 22, 2005.

Please amend the Application as follows:

Amendments to the Claims begin on page 2 of this Amendment.

Comments on Statement of Reasons for Allowance and Remarks begin on page 4 of

this Amendment.

HAYES SOLOWAY P.C. 3450 E. SUNRISE DRIVE, SUITE 140 TUCSON, AZ 85718 TEL. 520.882.7623 FAX. 520.882.7643

175 CANAL STREET MANCHESTER, NH 03101 TEL. 603.668.1400 FAX. 603.668.8567